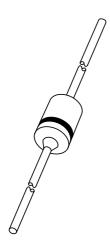
DISCRETE SEMICONDUCTORS

DATA SHEET



BYD11 seriesControlled avalanche rectifiers

Product specification Supersedes data of April 1996 1996 Sep 26



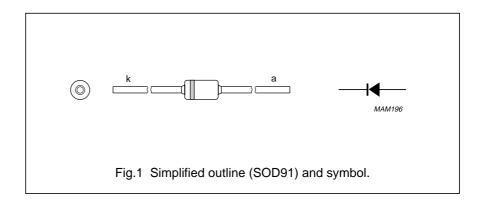


Controlled avalanche rectifiers

BYD11 series

FEATURES

- · Glass passivated
- High maximum operating temperature
- · Low leakage current
- · Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.



DESCRIPTION

Cavity free cylindrical glass package through Implotec^{™(1)} technology.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

MARKING

TYPE NUMBER	MARKING CODE
BYD11D	11D
BYD11G	11G
BYD11J	11J
BYD11K	11K
BYD11M	11M

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		_	600	V
	BYD11K		_	800	V
	BYD11M		_	1000	V
V _{RWM}	crest working reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		_	600	V
	BYD11K		_	800	V
	BYD11M		_	1000	V
V_R	continuous reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		_	600	V
	BYD11K		_	800	V
	BYD11M		_	1000	V

⁽¹⁾ Implotec is a trademark of Philips.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{F(AV)}	average forward current	T _{tp} = 55 °C; lead length = 10 mm; averaged over any 20 ms period; see Figs 2 and 4	_	0.50	A
		T _{amb} = 60 °C; PCB mounting (see Fig.9); averaged over any 20 ms period; see Figs 3 and 4	_	0.37	A
I _{FSM}	non-repetitive peak forward current	t = 10 ms half sinewave; $T_j = T_{j \text{ max}}$ prior to surge; $V_R = V_{RRMmax}$	_	10	A
P _{RSM}	non-repetitive peak reverse power dissipation	t = 20 μ s half sinewave; $T_j = T_{j \text{ max}}$ prior to surge	_	200	W
T _{stg}	storage temperature		-65	+175	°C
T _j	junction temperature	see Fig.5	-65	+175	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F tzt	forward voltage	$I_F = 0.5 \text{ A}; T_j = T_{j \text{ max}}; \text{ see Fig.6}$	_	_	0.91	V
		I _F = 0.5 A; see Fig.6	_	_	1.06	V
V _{(BR)R}	reverse avalanche breakdown voltage	I _R = 0.1 mA				
	BYD11D		225	_	_	V
	BYD11G		450	_	_	V
	BYD11J		650	_	_	V
	BYD11K		900	_	_	V
	BYD11M		1100	_	_	V
I _R	reverse current	V _R = V _{RRMmax} ; see Fig.7	_	_	1	μΑ
		$V_R = V_{RRMmax}$; $T_j = 165$ °C; see Fig.7	_	_	75	μΑ
t _{rr}	reverse recovery time	when switched from I_F = 0.5 A to I_R = 1 A; measured at I_R = 0.25 A; see Fig.10	_	3	_	μs
C _d	diode capacitance	V _R = 0 V; f = 1 MHz; see Fig.8	-	14	_	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length = 10 mm	180	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper \geq 40 μ m, see Fig.9. For more information please refer to the "General Part of associated Handbook".

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GRAPHICAL DATA

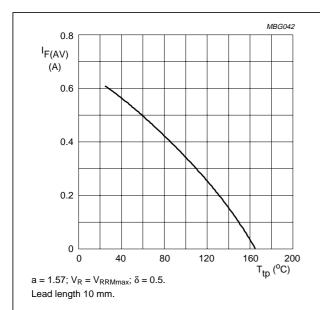


Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).

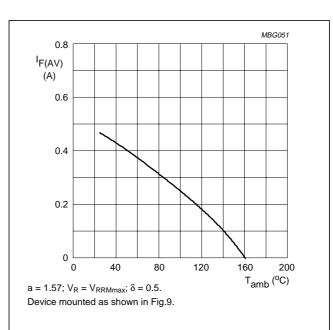


Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).

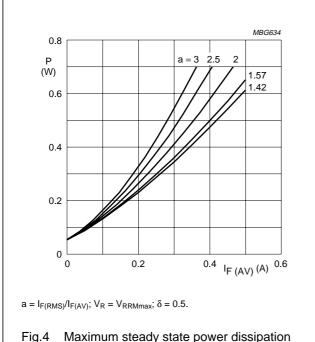
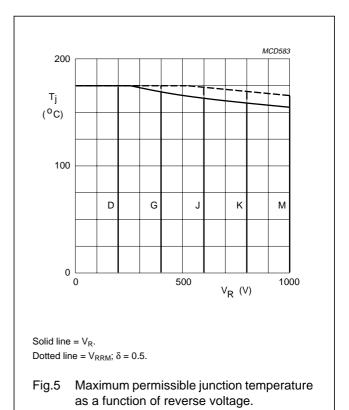
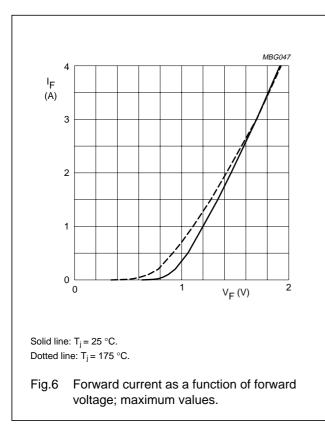


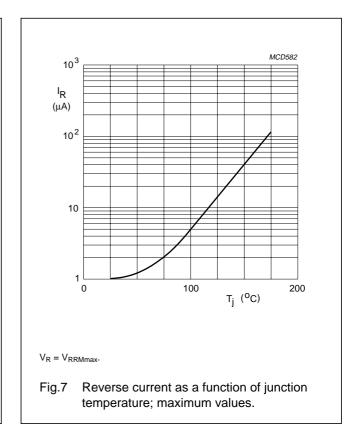
Fig.4 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.

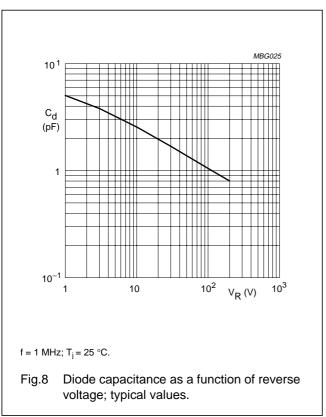


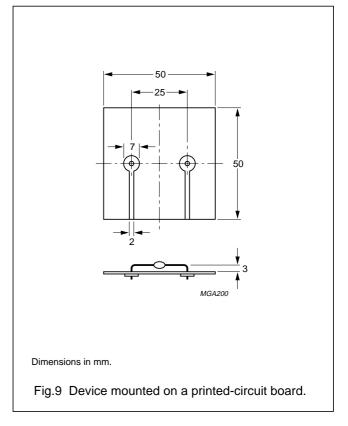
Controlled avalanche rectifiers

BYD11 series



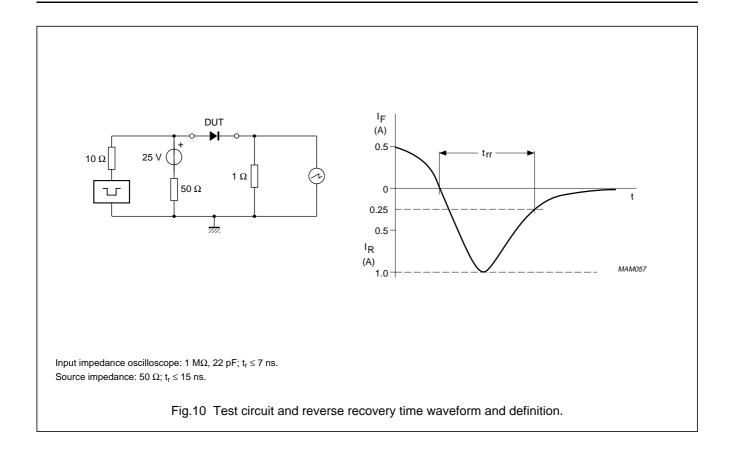






Controlled avalanche rectifiers

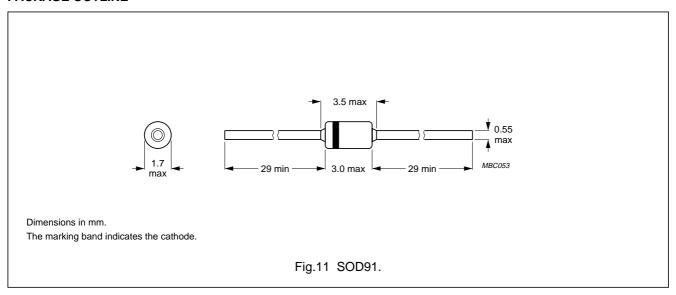
BYD11 series



Controlled avalanche rectifiers

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PACKAGE OUTLINE



DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.

Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.